Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	al:
Metal	
Overall Length:	
5.592 inches	
Function For Wh	ich Designed:
Rectifier	
Mounting Facility	/ Quantity:
1	
Joint Electronic	Device Engineering Council/jedec/case Outline Designation:
D0-30	
Electrode Interna	ally-electrically Connected To Case:
Collector	
Mounting Metho	d:
Threaded stud	
Features Provide	ed:
Hermetically seale	ed case
Overall Width Ac	ross Flats:
1.060 inches	
Thread Size:	
0.500 inches	
Semiconductor I	Naterial:
Silicon	
Voltage Rating In	Nolts Per Characteristic:
1200.0 nonrepeti	tive peak reverse voltage and 1000.0 repetitive peak reverse voltage and 1000.0 reverse voltage, instantaneou
Current Rating P	er Characteristic:
24.00 milliampere	s forward current, average major
Maximum Opera	ting Tempurature Per Measurement Point:
175.0 degrees cel	sius junction
Thread Series De	esignator:
Unf	
Terminal Type A	nd Quantity:
1 tab, solder lug	and 1 threaded stud
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	